

N-Channel 180 V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)		
180	0.042 at V _{GS} = 10 V	35		

FEATURES

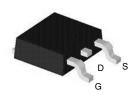
- DT-Trench Power MOSFET
- 100 % R_g and $\,$ IS Tested



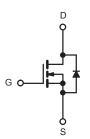
APPLICATIONS

· Primary Side Switch

TO-252 Pin Configuration



Top View



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)						
Parameter	Symbol	Limit	Unit			
Drain-Source Voltage		V _{DS}	180	V		
Gate-Source Voltage	V _{GS}	± 20				
Continuous Danis Comment /T = 475 °C\D	T _C = 25 °C		35			
Continuous Drain Current (T _J = 175 °C) ^b	T _C = 125 °C	l _D	19			
Pulsed Drain Current	I _{DM}	140	A			
Continuous Source Current (Diode Conduction)	Is	30	7			
Avalanche Current	I _{AS}	30				
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	24	mJ		
Mayimum Dayyar Dissination	T _C = 25 °C	В	85 ^b	W		
Maximum Power Dissipation	T _A = 25 °C	P _D	6 ^a	T VV		
Operating Junction and Storage Temperature Range	•	T _J , T _{stg}	- 55 to 175	°C		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Junction-to-Ambient ^a	t ≤ 10 s	- R _{thJA}	13	18	°C/W	
Junction-to-Ambient	Steady State		27	50		
Junction-to-Case (Drain)		R _{thJC}	0.85	1.1		

- Notes:
 a. Surface mounted on 1" x 1" FR4 board.
- b. See SOA curve for voltage derating.

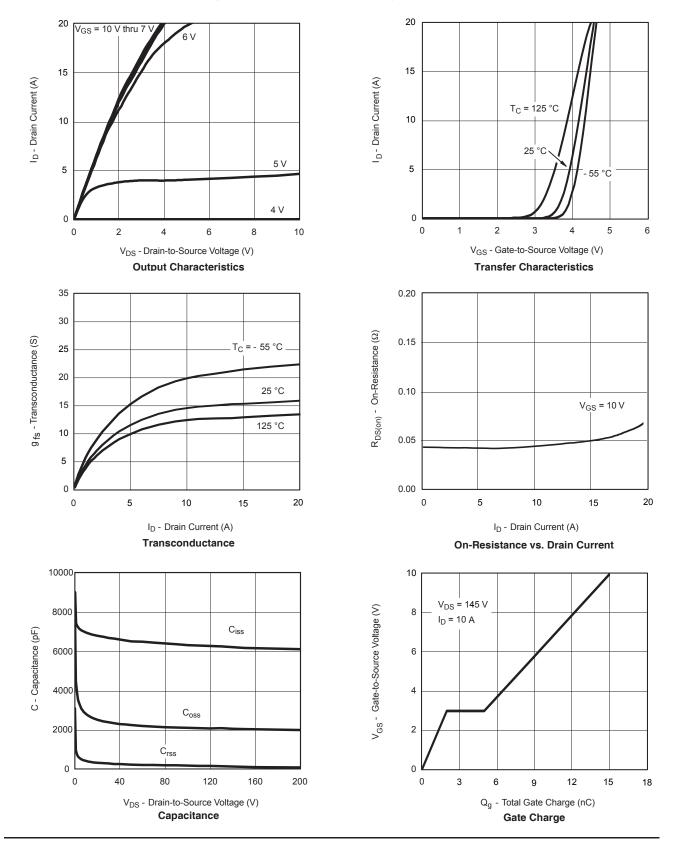
Parameter Symbol		Test Conditions	Min.	Typ. ^a	Max.	Unit	
Static							
rain-Source Breakdown Voltage V _{DS}		V _{GS} = 0 V, I _D = 250 uA 180				V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	2	4	4	V	
Gate-Body Leakage	I_{GSS} $V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$				± 100	nA	
		V _{DS} = 145 V, V _{GS} = 0 V			1		
Zero Gate Voltage Drain Current	I_{DSS}	V _{DS} = 145 V, V _{GS} = 0 V, T _J = 125 °C			50	uA	
		V _{DS} = 145 V, V _{GS} = 0 V, T _J = 175 °C			250	ı	
On-State Drain Current ^b	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	35			Α	
Drain-Source On-State Resistance ^b	R _{DS(on)}	V _{GS} = 10 V, I _D = 10 A		0.042	0.046	Ω	
Forward Transconductance ^b	orward Transconductance ^b 9 _{fs}			16		S	
Dynamic ^a							
Input Capacitance	C _{iss}			6750		pF	
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = 145 V, F = 1 MHz		1250			
Reverse Transfer Capacitance	C _{rss}			180			
Total Gate Charge ^c	Qg			15			
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 145 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 10 \text{ A}$		8		nC	
Gate-Drain Charge ^c	Q _{gd}			12		1	
Gate Resistance	R _g		1.2		2.9	Ω	
Turn-On Delay Time ^c	t _{d(on)}			11	27		
Rise Time ^c	t _r	$V_{DD} = 145 V, R_L = 5.2 \Omega$		34	76		
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong 10 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 2.5 \Omega$		22	48	ns	
Fall Time ^c	t _f			45	90		
Source-Drain Diode Ratings and Chara	acteristics (7	T _C = 25 °C)					
ontinous Source-Drain Diode Current I _S		T _C = 25 °C			30	^	
Pulsed Current	I _{SM}				140	Α	
Diode Forward Voltage ^b	V _{SD}	I _F = 19 A, V _{GS} = 0 V		0.7	1.5	V	
Source-Drain Reverse Recovery Time t_{rr} $I_F = 19 \text{ A}, \text{ dI/dt} = 100 \text{ A/os}$		I _F = 19 A, dI/dt = 100 A/òs		160	250	ns	

Notes:

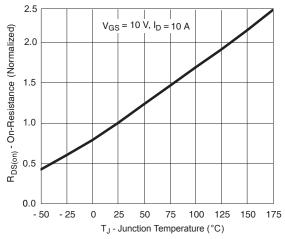
- a. Guaranteed by design, not subject to production testing.
- b. Pulse test; pulse width \leq 300 òs, duty cycle \leq 2 %. c. Independent of operating temperature.

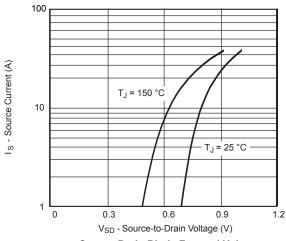
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



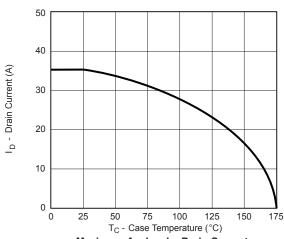
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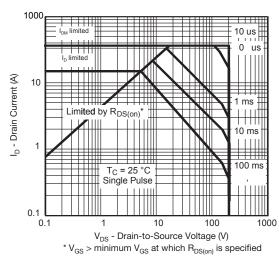




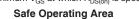
On-Resistance vs. Junction Temperature

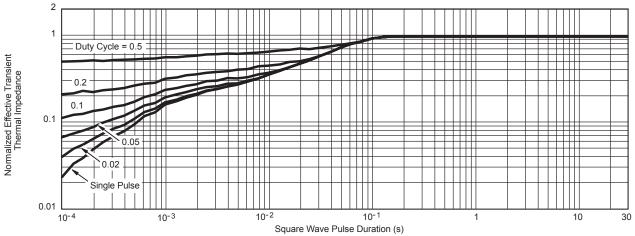






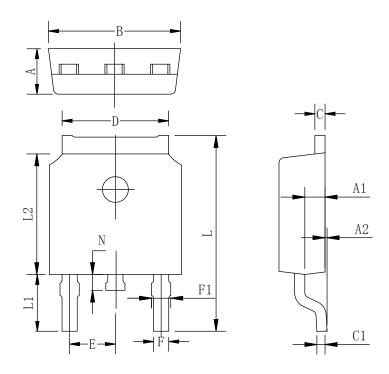
Maximum Avalanche Drain Current vs. Case Temperature





Normalized Thermal Transient Impedance, Junction-to-Case

TO-252-2L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

Symbol	Min	Тур	Max	
A	2.10	2.30	2.50	
A1	0.88	1.01	1.16	
A2	0.00	0.15	0.28	
В	6.40	6.60	6.80	
С	0.42	0.50	0.63	
C1	0.42	0.50	0.63	
D	5.08	5.32	5.65	
Е	2.286 TYP			
F	0.63	0.76	0.89	
F1	0.64	0.86	1.08	
L	9.30	9.90	10.80	
L1	2.4	2.8	3.6	
L2	5.90	6.10	6.55	
N	0.57	0.80	1.05	



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